

2N2195A	5	20 min.	25 ⁽²⁾	.25	1.3	30	50	5	0.6	2.8	—	—	—	—	—	Industrial Types.
2N2353A	4								.35	3.0						
11C7B1	8								1.5	5.0						
11C7F1	12								1.15	3.1						
11C207B20	20															
2N2243	5	40-120	80	.35	1.3	60	15	7	.8	2.8	30	20	15	20	—	Similar to 2N1893 but lower V _{CE(SAT)} .
2N2364	4								.4	5.0						
2N2243A	5	40-120	80	.25	1.3	60	15	7	.8	2.8	30	20	15	20	—	Similar to 2N1893 but lower V _{CE(SAT)} .
2N2364A	4								.4	5.0						
11C710	19								.3	1.0						
11C10B1	8								1.5	5.0						
11C10F1	12								1.15	3.1						
11C210B20	20								1.0	5.0						
2N2868	5	40-120	40	.25	1.3	30	15	5	.8	2.8	30	20	—	20	—	—
2N2909	4								.4	5.0						
11C11B1	8								1.5	5.0						
11C11F1	12								1.15	3.1						
11C211B20	20								1.0	5.0						
11C1536	3	40-120	30 ⁽²⁾	.3	1.3	30	25	6	0.8	2.8	—	—	—	15	—	—
4JD12X043	21	Two 2N2193 transistors in a six lead TO-5 package.														
4JD12X047	21	Two 2N2195 transistors in a six lead TO-5 package.														

Kovar Tab (See Outline Drawing No. 18)

11C551 ⁽⁶⁾	100-300 ⁽⁴⁾	—	0.25 ⁽⁵⁾	0.9 ⁽⁵⁾	30	15	5	100mw	—	100-300	—	75	—	—	—	Kovar Tab of 2N2192, A
11C553 ⁽⁶⁾	40-120 ⁽⁴⁾	—	0.25 ⁽⁵⁾	0.9 ⁽⁵⁾	30	15	7	100mw	—	40-120	—	30	—	—	—	Kovar Tab of 2N2193, A
11C557 ⁽⁶⁾	30-150 ⁽⁴⁾	—	0.25 ⁽⁵⁾	0.9 ⁽⁵⁾	30	50	5	100mw	—	30-150	—	—	—	—	—	Kovar Tab of 2N2195, A

NOTES: Test Conditions in Italics

(1) Typical f_t for all types \approx 130 Mc.

(2) V_{CEO}

(3) For switching and amplifier applications.

(4) $h_{FE} = I_C = 10$ ma, V_{CE} = 10V.

(5) I_C = 50 ma, I_B = 5 ma.

(6) Storage Temperature on all types is -65°C to +300°C. Operating Temperature on all types is -65°C to +200°C.

continued on next page